Silicon NPN Phototransistor Version 1.3

SFH 309



Features:

• Spectral range of sensitivity: (typ) 380 ... 1150 nm

• Package: 3mm Radial (T 1), Epoxy

Special: High photosensitivity

High linearity

· Available in groups

Applications

Photointerrupters

· Industrial electronics

· For control and drive circuits

Ordering Information

Туре:	Photocurrent I _{PCE} [µA]	Ordering Code
	$\lambda = 950 \text{ nm}, E_e = 0.5 \text{ mW/cm}^2, V_{CE} = 5 \text{ V}$	
SFH 309	400 5000	Q62702P0859
SFH 309-3/4	630 2000	Q62702P3592
SFH 309-4	1000 2000	Q62702P0998
SFH 309-4/5	1000 3200	Q62702P3593
SFH 309-5	1600 3200	Q62702P0999
SFH 309-5/6	1600 5000	Q62702P3594

Note: Only one bin within one packing unit (variation less than 2:1)



$\underline{\text{Maximum Ratings } (T_A = 25 \, ^{\circ}\text{C})}$

Parameter	Symbol	Values	Unit
Operating and storage temperature range	T _{op} ; T _{stg}	-40 100	°C
Collector-emitter voltage	V _{CE}	35	V
Collector current	I _C	15	mA
Collector surge current (τ < 10 μs)	I _{CS}	75	mA
Total Power dissipation	P _{tot}	165	mW
Thermal resistance	R _{thJA}	450	K/W
ESD withstand voltage (acc. to ANSI/ ESDA/ JEDEC JS-001 - HBM)	V _{ESD}	2000	V

Characteristics ($T_A = 25 \, ^{\circ}C$)

Parameter		Symbol	Values	Unit
Wavelength of max. sensitivity	(typ)	$\lambda_{\text{S max}}$	860	nm
Spectral range of sensitivity	(typ)	λ _{10%}	(typ) 380 1150	nm
Radiant sensitive area (Ø 220 µm)	(typ)	А	0.038	mm ²
Dimensions of chip area	(typ)	LxW	(typ) 0.45 x 0.45	mm x mm
Distance chip front to case surface	(min max)	Н	(min max) 2.4 2.8	mm
Half angle	(typ)	φ	± 12	0
Capacitance (V _{CE} = 0 V, f = 1 MHz, E = 0)	(typ)	C _{CE}	5	pF
Dark current (V _{CE} = 20 V, E = 0)	(typ (max))	I _{CE0}	1 (≤ 50)	nA



Grouping (T_A = 25 °C, λ = 950 nm)

Group	Min Photocurrent	Max Photocurrent	Typ Photocurrent	Rise and fall time
	$E_e = 0.5 \text{ mW/cm}^2,$ $V_{CE} = 5 \text{ V}$	$E_e = 0.5 \text{ mW/cm}^2,$ $V_{CE} = 5 \text{ V}$	E _V = 1000 lx, Std. Light A, V _{CE} = 5 V	
	I _{PCE, min} [μA]	I _{PCE, max} [μA]	I _{PCE} [μΑ]	t _r , t _f [μs]
-2	400	800	1500	5
-3	630	1250	2800	6
-4	1000	2000	4500	7
-5	1600	3200	7200	8
-6	2500	5000	11200	9

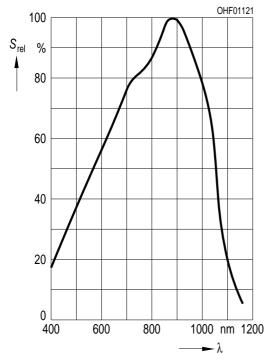
Group	Collector-emitter saturation voltage
	$I_C = I_{PCEmin} \times 0.3$, $E_e = 0.5 \text{ mW/cm}^2$
	V _{CEsat} [mV]
-2	200
-3	200
-4	200
-5	200
-6	200

Note.: I_{PCEmin} is the min. photocurrent of the specified group.



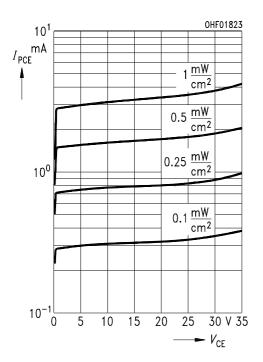
Relative Spectral Sensitivity 1) page 9

 $S_{rel} = f(\lambda)$



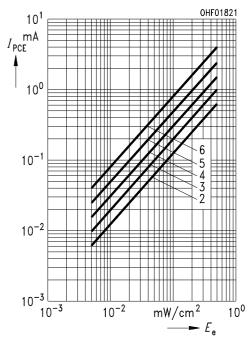
Photocurrent 1) page 9

 $I_{PCE} = f(V_{CE}), E_e = Parameter$



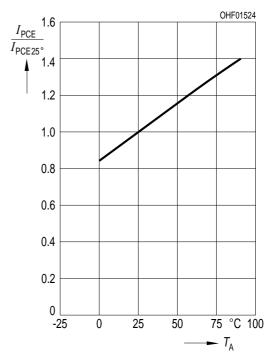
Photocurrent 1) page 9

 $I_{PCE} = f(E_e), V_{CE} = 5 V$



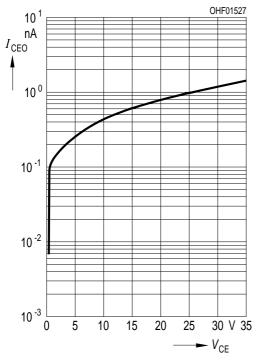
Photocurrent 1) page 9

 $I_{PCE} / I_{PCE} (25^{\circ}C) = f(T_A), V_{CE} = 5 \text{ V}$



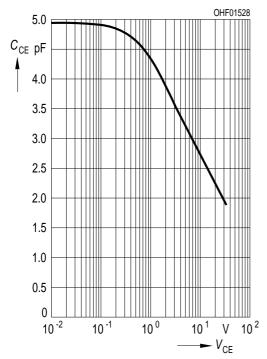
Dark Current 1) page 9

$$\mathsf{I}_\mathsf{CEO} = \mathsf{f}(\mathsf{V}_\mathsf{CE}),\,\mathsf{E} = 0$$



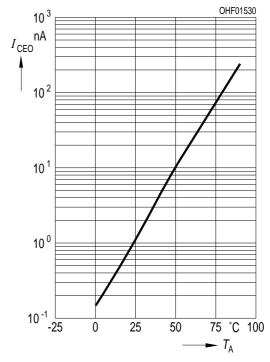
Collector-Emitter Capacitance 1) page 9

$$C_{CE} = f(V_{CE}), f = 1 MHz, E = 0$$



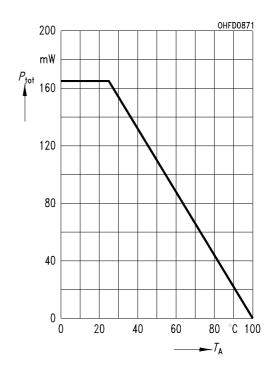
Dark Current 1) page 9

$$I_{CE0} = f(T_A), V_{CE} = 20 \text{ V}, E = 0$$



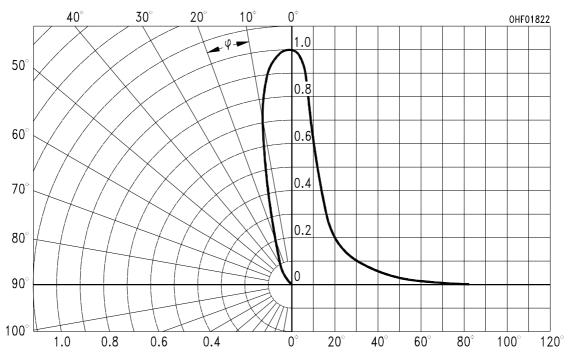
Power Consumption

$$P_{tot} = f(T_A)$$

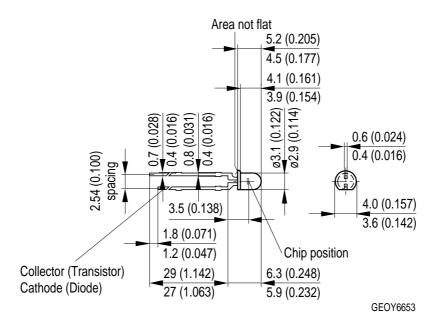


Directional Characteristics 1) page 9

$$S_{rel} = f(\phi)$$



Package Outline



Dimensions in mm (inch).

Package

3mm Radial (T 1), Epoxy



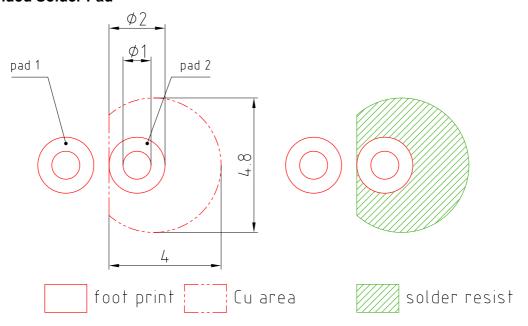
Approximate Weight:

0.2 g

Note

Packing information is available on the internet (online product catalog).

Recommended Solder Pad



E062.3010.188-01

Dimensions in mm.

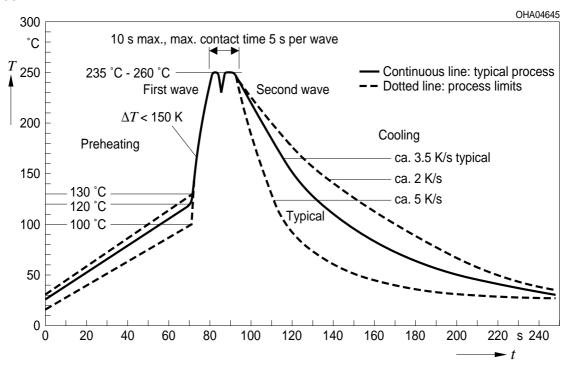
Note:

pad 1: emitter



TTW Soldering

IEC-61760-1 TTW



Disclaimer

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

Attention please!

The information describes the type of component and shall not be considered as assured characteristics.

Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version in the Internet.

Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

Components used in life-support devices or systems must be expressly authorized for such purpose!

Critical components* may only be used in life-support devices** or systems with the express written approval of OSBAM OS

- *) A critical component is a component used in a life-support device or system whose failure can reasonably be expected to cause the failure of that life-support device or system, or to affect its safety or the effectiveness of that device or system.
- **) Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health and the life of the user may be endangered.



Glossary

Typical Values: Due to the special conditions of the manufacturing processes of LED, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.



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